

HMC190AMS8 / 190AMS8E

GaAs MMIC SPDT SWITCH DC - 3 GHz

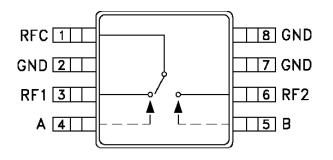


Typical Applications

The HMC190AMS8(E) is ideal for:

- MMDS & WirelessLAN
- Portable Wireless

Functional Diagram



Features

Low Insertion Loss: 0.4 dB
Ultra Small Package: MSOP8
High Input IP3: +50 dBm
Positive Control: 0/+3V @ 3 µA

General Description

The HMC190AMS8(E) is a low cost SPDT switch in a 8-lead MSOP package. The switch can control signals from DC to 3 GHz. It is especially suited for low and medium power applications using positive control voltages. The two control voltages require a minimal amount of DC current, which is optimal for battery powered radio systems at 0.9, 1.9, and 2.4 GHz. The HMC190AMS8(E) provides exceptional third order intermodulation performance of +50 dBm. The design has been optimized for the small MSOP package, and maintains a VSWR of better than 1.2:1 up to 2 GHz. This device is the positive control MSOP8 packaged version of our HMC239S8 negative control device.

Electrical Specifications, $T_A = +25^{\circ}$ C, VctI = 0/+3 to +8 Vdc

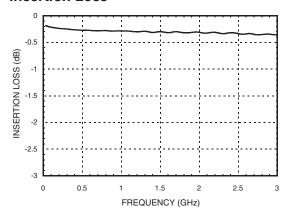
Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		0.4 0.4 0.5 0.7	0.6 0.6 0.8 1.0	dB dB dB dB
Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	23 23 22 19	27 27 26 22		dB dB dB dB
Return Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	24 20 15 10	28 28 20 16		dB dB dB dB
Input Power for 1 dB Compression (Vctl = 0/+5V)	0.5 - 1.0 GHz 0.5 - 3.0 GHz	25 23	30 29		dBm dBm
Input Third Order Intercept (Vctl = 0/+5V)(Two-tone Input Power = +7 dBm Each Tone)	0.5 - 1.0 GHz 0.5 - 3.0 GHz	45 44	50 49		dBm dBm
Switching Characteristics	DC - 3.0 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)			3 10		ns ns

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com
Application Support: Phone: 978-250-3343 or apps@hittite.com

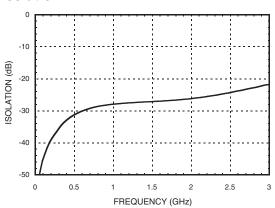




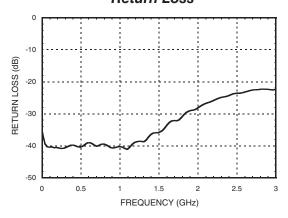
Insertion Loss



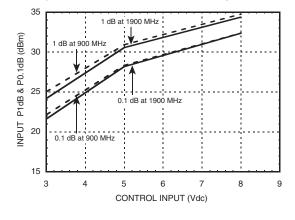
Isolation



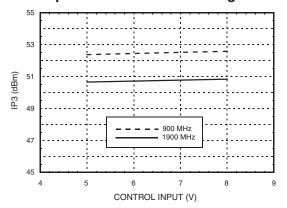
Return Loss



Input 0.1 and 1.0 dB Compression vs. Control Voltage



Input Third Order Intercept Point vs. Control Voltage







Distortion vs. Control Voltage

Control Input	Third Order Intercept (dBm) +7 dBm Each Tone	
(Vdc)	900 MHz	1900 MHz
+5	52	50
+8	52	51

Compression vs. Control Voltage

	Carrier at 900 MHz		Carrier at 1900 MHz		
Control Input	Input Power for 0.1 dB Compression	Input Power for 1.0 dB Compression	Input Power for 0.1 dB Compression	Input Power for 1.0 dB Compression	
(Volts)	(dBm)	(dBm)	(dBm)	(dBm)	
+3	21	24	22	25	
+5	27	30	27	31	
+8	32	34	32	34	

Truth Table

*Control Input Voltage Tolerances are ± 0.2 Vdc.

Contro	I Input*	Control Current		Signal Path State		
A (Vdc)	B (Vdc)	Ia (μΑ)	lb (μΑ)	RF to RF1	RF to RF2	
0	+3	-3	3	ON	OFF	
+3	0	3	-3	OFF	ON	
0	+5	-5	5	ON	OFF	
+5	0	5	-5	OFF	ON	
0	+8	-32	32	ON	OFF	
+8	0	32	-32	OFF	ON	

Caution: Do not operate in 1 dB compression at power levels above +31 dBm (Vctl = +5 Vdc) and do not "hot switch" power levels greater than +20dBm (VctI = +5 Vdc).

DC blocks are required at ports RFC, RF1 and RF2.





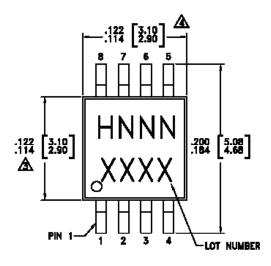
Absolute Maximum Ratings

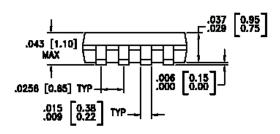
Max. Input Power V _{CTL} = 0/+8V	0.5 GHz 0.5 - 2 GHz	+27 dBm +34 dBm	
Control Voltage Range (A & B)		-0.2 to +12 Vdc	
Storage Temperature		-65 to +150 °C	
Operating Temperature		-40 to +85 °C	
ESD Sensitivity (HBM)		Class 1A	

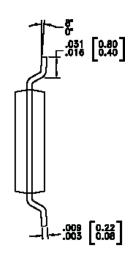


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing







NOTES:

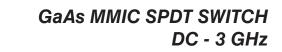
- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

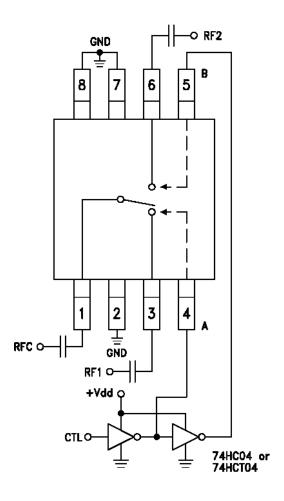
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC190AMS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H190A XXXX
HMC190AMS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H190A XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





Typical Application Circuit



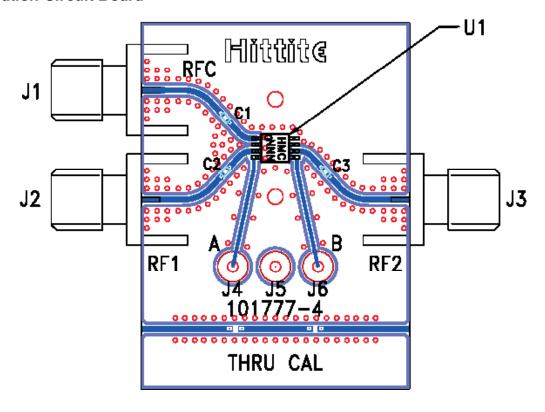
Notes

- 1. Set logic gate and switch Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
- 2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of 5 to 8 Volts applied to the CMOS logic gates.
- 3. DC blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
- 4. Highest RF signal power capability is achieved with Vdd = +8V and A/B set to 0/+8V.





Evaluation Circuit Board



List of Materials for Evaluation PCB 101779 [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J6	DC Pin
C1 - C3	330 pF Capacitor, 0402 Pkg.
U1	HMC190AMS8(E) SPDT Switch
PCB [2]	101777 Evaluation PCB

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

^[2] Circuit Board Material: Rogers 4350